NSN 5961-01-321-1915

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| Inclosure Material: |
|---|
| |
| Metal Overall Langethy |
| Overall Length: |
| 0.500 inches |
| Terminal Length: |
| 0.312 inches |
| Overall Diameter: 1.250 inches |
| |
| Mounting Facility Quantity: |
| 1 Internal Configuration: |
| Internal Configuration: |
| Junction contact |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| To-67 |
| Mounting Method: |
| Threaded hole and terminal |
| Features Provided: |
| Hermetically sealed case |
| Thread Size: |
| 0.190 inches |
| Semiconductor Material: |
| Germanium M. M. D. G. M. M. D. G. M. M. M. D. G. M. |
| Voltage Rating In Volts Per Characteristic: |
| 70.0 breakdown voltage, collector-to-emitter, base open |
| Current Rating Per Characteristic: |
| 10.00 amperes source cutoff current |
| Power Rating Per Characteristic: |
| 70.0 watts small-signal input power, common-collector absolute |
| Transfer Ratio: |
| 25.0 static forward current transfer ratio, common-emitter and 50.0 static forward current transfer ratio, common-emitter |
| Maximum Operating Tempurature Per Measurement Point: |
| 100.0 degrees celsius junction |
| Special Features: |
| Junction pattern arrangement: pnp |
| Thread Series Designator: |
| Unf |
| Terminal Type And Quantity: |
| 2 pin and 1 threaded stud |
| Shelf Life: |
| N/a |
| Unit Of Measure: |

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Demilitarization:

No

Fiig:

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